



# ***Alpha & Omega Semiconductor Product Reliability Report***

**AOZ9510QI**, rev A

**Plastic Encapsulated Device**

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This AOS product reliability report summarizes the qualification results for AOZ9510QI in QFN4x4B-23L package. Accelerated environmental tests are performed on a specific sample size and samples are electrically tested before and after each time point. Review of final electrical test results confirm that AOZ9510QI pass the AOS quality and reliability requirements. The released products will be categorized by its process family and routinely monitored for continuous improvement of product quality.

## I. Reliability Stress Test Summary and Results

Test Item	Test Condition	Time Point	Total Sample Size	Number of Failures	Reference Standard
HTOL	$T_J = 125^{\circ}\text{C}$ , $V_{IN} = V_{ccmax}$	168 / 500 / 1000 hours	231 pcs	0	JESD22-A108
Preconditioning (Note A)	$T_A = 30^{\circ}\text{C}$ , RH = 60% + 3 cycle reflow @ $260^{\circ}\text{C}$ (MSL 3)	192 hours	693 pcs	0	JESD22-A113
HAST	$T_A = 130^{\circ}\text{C}$ , RH = 85%, P = 33.3psia, $V_{IN} = V_{ccmax}$	96 hours	231 pcs	0	JESD22-A110
Autoclave	$T_A = 121^{\circ}\text{C}$ , RH = 100%, P = 29.7psia	96 hours	231 pcs	0	JESD22-A102
Temperature Cycle	$T_A = -65^{\circ}\text{C}$ to $150^{\circ}\text{C}$ , air to air	250 / 500 / 1000 cycles	231 pcs	0	JESD22-A104

**Note:** The reliability data presents total of available generic data up to the published date.

Note A: MSL (Moisture Sensitivity Level) 3 based on J-STD-020

## II. Reliability Evaluation

**FIT rate (per billion): 50.97**

**MTTF = 2240 years**

The presentation of FIT rate for the individual product reliability is restricted by the actual burn-in sample size. Failure Rate Determination is based on JEDEC Standard JESD 85. FIT means one failure per billion hours.

**Failure Rate** =  $\text{Chi}^2 \times 10^9 / [2 (N) (H) (Af)] = 50.97$

**MTTF** =  $10^9 / \text{FIT} = 2240$  years

**Chi<sup>2</sup>** = Chi Squared Distribution, determined by the number of failures and confidence interval

**N** = Total Number of units from burn-in tests

**H** = Duration of burn-in testing

**Af** = Acceleration Factor from Test to Use Conditions ( $E_a = 0.7\text{eV}$  and  $T_{use} = 55^{\circ}\text{C}$ )

Acceleration Factor [**Af**] =  $\text{Exp} [E_a / k (1/T_{j u} - 1/T_{j s})]$

**Acceleration Factor ratio list:**

	55 deg C	70 deg C	85 deg C	100 deg C	115 deg C	125 deg C
Af	77	26	9.8	3.9	1.7	1

**T<sub>j s</sub>** = Stressed junction temperature in degree (Kelvin),  $K = C + 273.16$

**T<sub>j u</sub>** = The use junction temperature in degree (Kelvin),  $K = C + 273.16$

**k** = Boltzmann's constant,  $8.617164 \times 10^{-5} \text{eV} / \text{K}$

### III. ESD and Latch Up Test Results

Test	Test Conditions	Total Sample Size	Number of Failures	Reference Standard
Electrostatic Discharge Human Body Model	T <sub>A</sub> = 25°C, +/-2kV	3	0	JESD-A114
Electrostatic Discharge Charged Device Model	T <sub>A</sub> = 25°C, +/-1kV	3	0	JESD-C101
Latch Up	T <sub>A</sub> = 25°C, +/-200mA, 30V	6	0	JESD78
Latch Up	T <sub>A</sub> = 85°C, +/-200mA, 30V	6	0	JESD78

(1) ATE results are used to determine PASS/FAIL. Parametric shift <10%.

